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Kind regards,

Team Nexperia

PDTA123Y series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 10 k Ω

Rev. 04 — 3 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET).

Table 1. Product overview

Type number	Package	Package			
	NXP	JEITA	JEDEC	complement	
PDTA123YE	SOT416	SC-75	-	PDTC123YE	
PDTA123YK	SOT346	SC-59A	TO-236	PDTC123YK	
PDTA123YM	SOT883	SC-101	-	PDTC123YM	
PDTA123YS[1]	SOT54	SC-43A	TO-92	PDTC123YS	
PDTA123YT	SOT23	-	TO-236AB	PDTC123YT	
PDTA123YU	SOT323	SC-70	-	PDTC123YU	

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General purpose switching and amplification
- Inverter and interface circuits

Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current (DC)		-	-	-100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	$k\Omega$
R2/R1	bias resistor ratio		3.6	4.5	5.5	

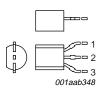


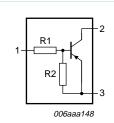
2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		R1 2
3	GND (emitter)	001aab347	R2 R2 3

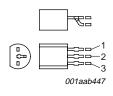
1	input (base)
2	output (collector)
3	GND (emitter)

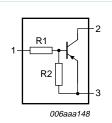




SOT54 variant

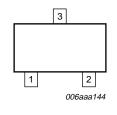
1	input (base)
2	output (collector)
3	GND (emitter)

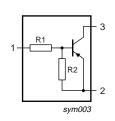




SOT23, SOT323, SOT346, SOT416

1	input (base)
2	GND (emitter)
3	output (collector)

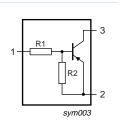




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





PDTA123Y_SER_4

3. Ordering information

Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
PDTA123YE	SC-75	plastic surface mounted package; 3 leads	SOT416		
PDTA123YK	SC-59A	plastic surface mounted package; 3 leads	SOT346		
PDTA123YM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883		
PDTA123YS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54		
PDTA123YT	-	plastic surface mounted package; 3 leads	SOT23		
PDTA123YU	SC-70	plastic surface mounted package; 3 leads	SOT323		

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

4. Marking

Table 5. Marking codes

rabio or marking ocuso	
Type number	Marking code[1]
PDTA123YE	14
PDTA123YK	13
PDTA123YM	G2
PDTA123YS	TA123Y
PDTA123YT	*AD
PDTA123YU	*13

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	- 5	V
V_{I}	input voltage				
	positive		-	+5	V
	negative		-	-12	V
Io	output current (DC)		-	-100	mA
I _{CM}	peak collector current		-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	SOT416		<u>[1]</u> _	150	mW
	SOT346		<u>[1]</u> _	250	mW
	SOT883		[2][3]	250	mW
	SOT54		<u>[1]</u> -	500	mW
	SOT23		<u>[1]</u> -	250	mW
	SOT323		[1] -	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Refer to standard mounting conditions.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		[1] _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> -	-	250	K/W
	SOT23		<u>[1]</u> -	-	500	K/W
	SOT323		<u>[1]</u> -	-	625	K/W

^[1] Refer to standard mounting conditions.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

^[2] Reflow soldering is the only recommended soldering method.

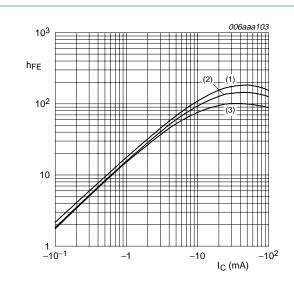
^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

7. Characteristics

 Table 8.
 Characteristics

T_{amb} = 25 °C unless otherwise specified

GIIID						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μΑ
		$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	–50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-700	μΑ
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	35	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	-	-	-150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.75	-0.3	V
V _{I(on)}	on-state input voltage	$V_{CE} = -300 \text{ mV}; I_{C} = -20 \text{ mA}$	-2.5	-1.15	-	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		3.6	4.5	5.5	
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz	-	-	2	pF



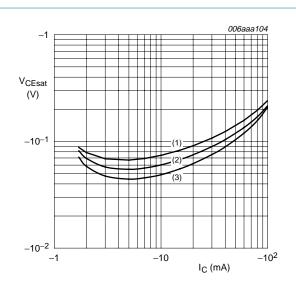
$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



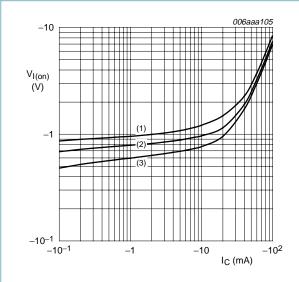
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



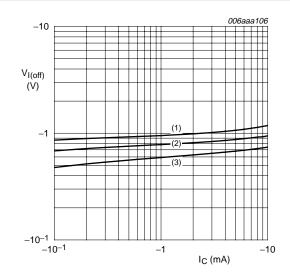
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = -5 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 4. Off-state input voltage as a function of collector current; typical values

8. Package outline

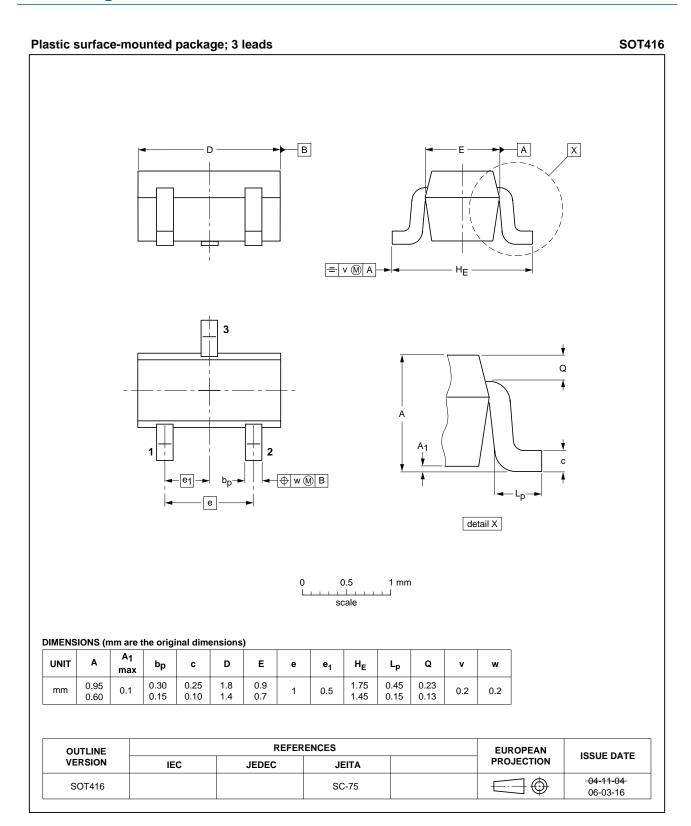


Fig 5. Package outline SOT416 (SC-75)

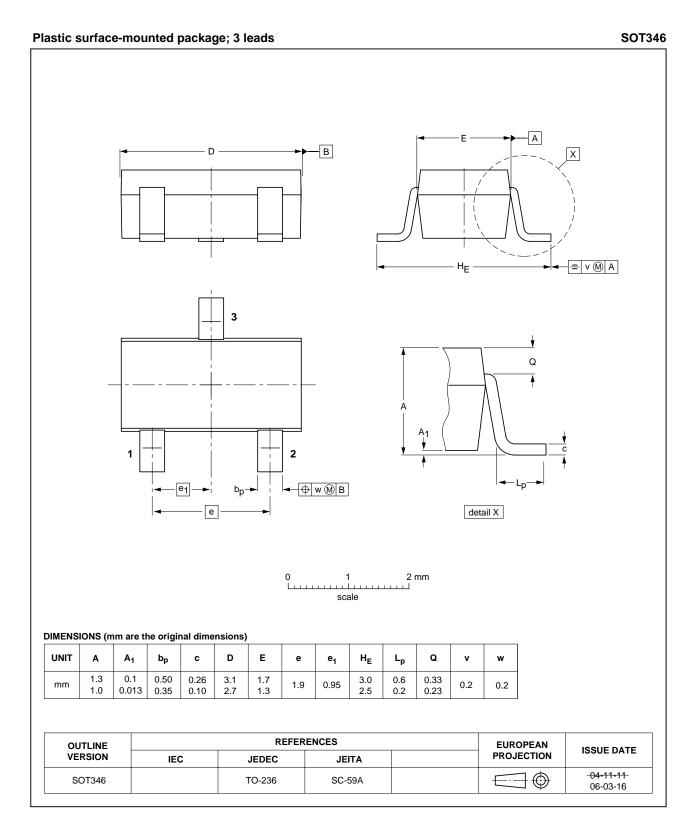


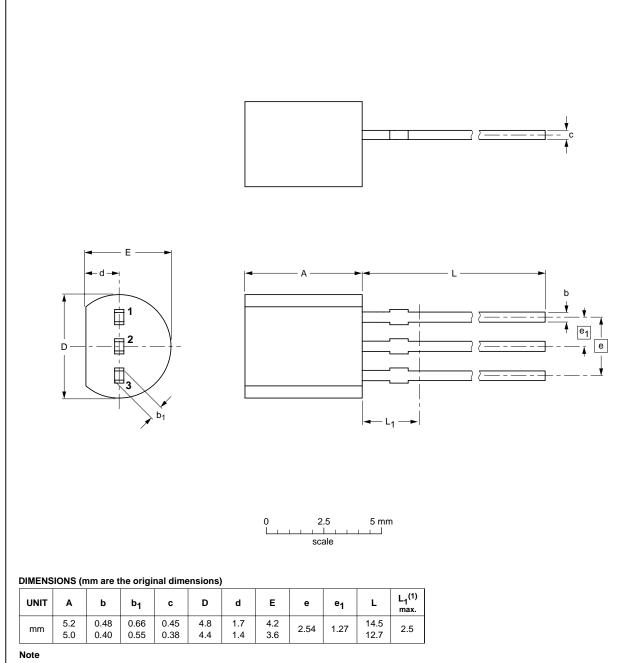
Fig 6. Package outline SOT346 (SC-59A/TO-236)

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm **SOT883** e₁ 1 mm **DIMENSIONS (mm are the original dimensions)** A₁ max. UNIT b b_1 D Ε е L L_1 0.50 0.20 0.55 0.62 0.30 0.30 1 02 mm 0.03 0.35 0.46 0.47 0.12 0.55 0.95 0.22 0.22 1. Including plating thickness REFERENCES OUTLINE **EUROPEAN ISSUE DATE** VERSION **PROJECTION** JEDEC 03-02-05 \bigcirc SOT883 SC-101 03-04-03

Fig 7. Package outline SOT883 (SC-101)

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			-04-06-28- 04-11-16

Fig 8. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A

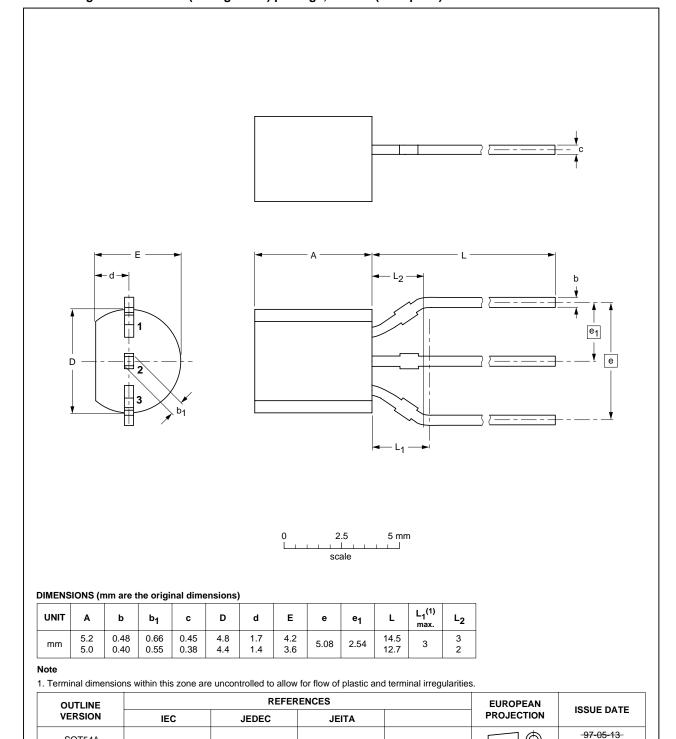


Fig 9. Package outline SOT54A

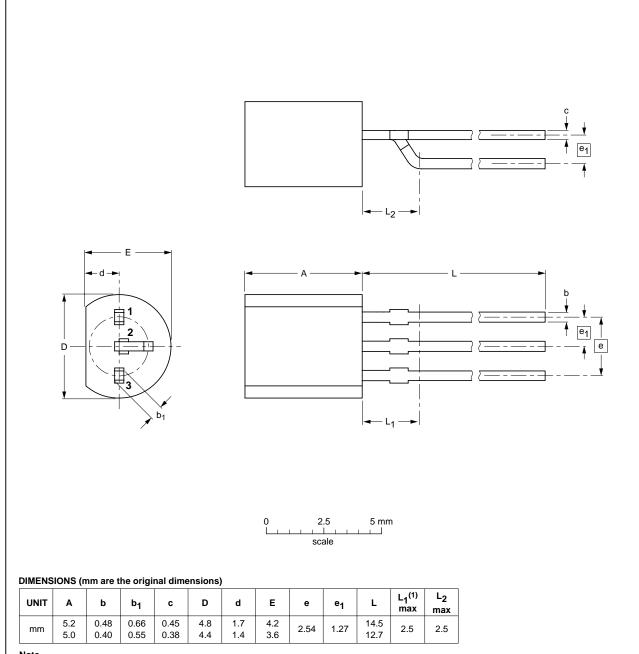
SOT54A

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04-06-28

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant



1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT54 variant						-04-06-28 05-01-10	

Fig 10. Package outline SOT54 variant

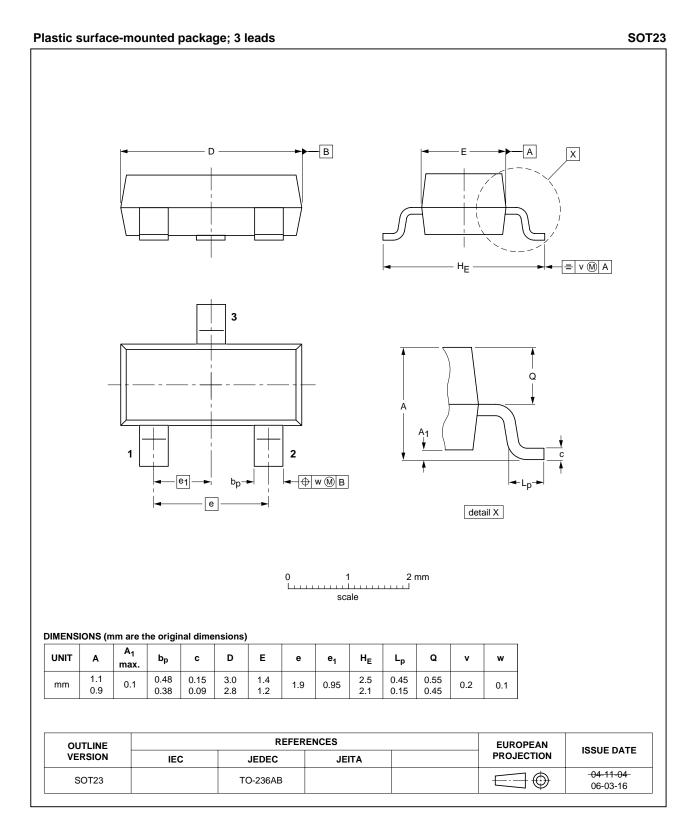


Fig 11. Package outline SOT23 (TO-236AB)

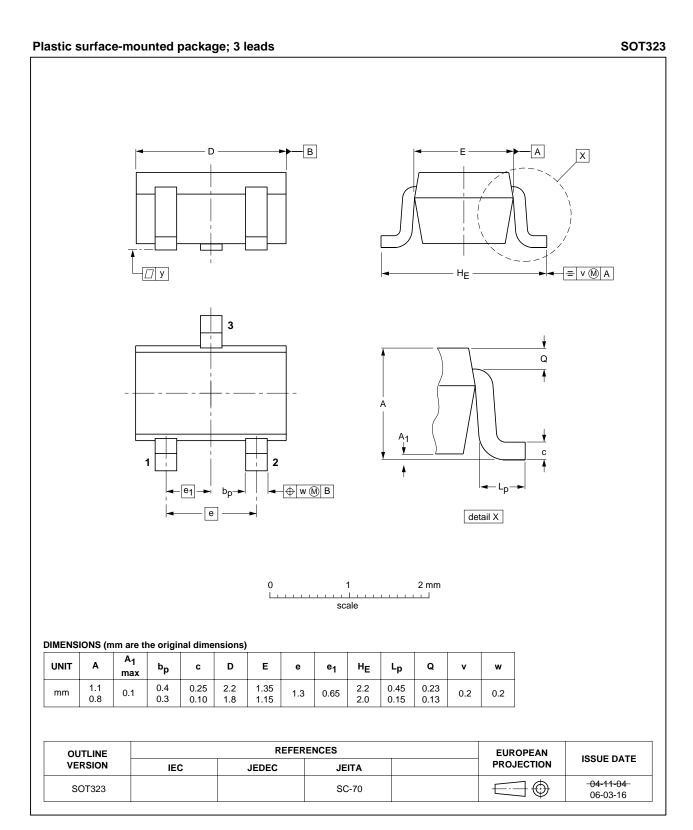


Fig 12. Package outline SOT323 (SC-70)

9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.

Type number	Package	Description	Packing (Packing quantity		
			3000	5000	10000	
PDTA123YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123YK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA123YS	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide patch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTA123YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTA123YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA123Y_SER_4	20090903	Product data sheet	-	PDTA123Y_SER_3
Modifications: • This data sheet was changed to reflect the new compan including new legal definitions and disclaimers. No chan content				
	 Figure 5 "Pa 	ackage outline SOT416 (SC	<u>-75)"</u> : updated	
	Figure 6 "Pa	ackage outline SOT346 (SC	-59A/TO-236)": update	ed
	Figure 11 "F	Package outline SOT23 (TO	-236AB)": updated	
	Figure 12 "F	Package outline SOT323 (So	C-70)": updated	
PDTA123Y_SER_3	20050405	Product data sheet	-	PDTA123YT_2
PDTA123YT_2	20040611	Objective data sheet	-	PDTA123YT_1
PDTA123YT_1	20040325	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTA123Y series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 10 k Ω

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